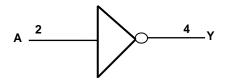


# **Pin Descriptions**

Pin Name	Pin NO.	Description	
NC	1	No Connection	
Α	2	Data Input	
GND	3	Ground	
Y	4	Data Output	
V <sub>CC</sub>	5	Supply Voltage	

# **Logic Diagram**



# **Function Table**

Inputs	Output
Α	Υ
Н	L
L	Н



# **Absolute Maximum Ratings (Note 2)**

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
$V_{CC}$	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> <0	-20	mA
lok	Output Clamp Current (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20	mA
Io	Continuous output current (V <sub>O</sub> = 0 to V <sub>CC</sub> )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

# **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit
V <sub>CC</sub>	Operating Voltage		2	5.5	V
		V <sub>CC</sub> = 2V	1.7		
$V_{IH}$	High-level Input Voltage	V <sub>CC</sub> = 3V	2.4		V
		V <sub>CC</sub> = 5.5V	4.4		
		V <sub>CC</sub> = 2V		0.3	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 3V		0.6	V
		V <sub>CC</sub> = 5.5V		1.1	
VI	Input Voltage	·	0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 2V		-50	uA
$I_{OH}$	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-3	
		$V_{CC} = 5V \pm 0.5V$		-6	mA mA
		V <sub>CC</sub> = 2V		50	uA
$I_{OL}$	Low-level output current	$V_{CC} = 5V \pm 0.5V$		3	
		V <sub>CC</sub> = 3V		6	mA mA
$T_A$	Operating free-air temperature		-40	85	°C

Notes: 3. Unused inputs should be held at  $V_{\mbox{CC}}$  or Ground.



## **Electrical Characteristics**

Compleal	Downwoodow	Took Conditions	V		25°C		-40°C t	o 85ºC	-40°C to	125ºC	l lmit
Symbol	Parameter	Test Conditions	itions V <sub>CC</sub>		Тур.	Max	Min	Max	Min	Max	Unit
			2V	1.8	2		1.75		1.75		
	High Level	$I_{OH} = -50\mu A$	3V	2.7	3		2.65		2.65		
$V_{OH}$	Output		4.5V	4.0	4.5		3.9		3.9		V
	Voltage	$I_{OH} = -3mA$	3V	2.58			2.5		2.5		
		$I_{OH} = -6mA$	4.5V	3.94			3.8		3.8		
			2V			0.2		0.2		0.2	
	Low Level	$I_{OL} = 50\mu A$	3V			0.3		0.3		0.3	
$V_{OL}$	Output		4.5V			0.5		0.5		0.5	V
	Voltage	$I_{OL} = 3mA$	3V			0.36		0.44		0.55	
		$I_{OL} = 6mA$	4.5V			0.36		0.44		0.55	
II	Input Current	$V_I = 5.5V$ or GND	0 to 5.5V			± 0.1		± 1		± 2	μΑ
Icc	Supply Current	$V_I = 5.5V$ or GND $I_O=0$	5.5V			1		10		40	μA
Cı	Input Capacitance	$V_I = V_{CC} - \text{or GND}$	5.5V		2.0	10		10		10	pF
$\theta_{JA}$	Thermal Resistance	SOT25	(Note 4)		195						°C/W
OJA	Junction-to- Ambient	SOT353	(14010-1)		430						] 3, 11
Ala	Thermal Resistance	SOT25	(Note 4)		58						°C // //
θ <sub>JC</sub>	Junction-to- Case	SOT353	(Note 4)		155						°C/W

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

# **Switching Characteristics**

#### $V_{CC} = 3.3V \pm 0.3$ (see Figure 1)

Parame	tor	From	ТО			25°C		-40°C t	o 85ºC	-40°C to	125ºC	Unit
Parame	tei	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Ollit
4		۸	V	C <sub>L</sub> =15pF	0.6	3.4	7.1	0.6	8.5	0.6	10.0	ns
<b>ι</b> pd		A	Y	C <sub>L</sub> =50pF	0.6	4.9	10.6	0.6	12.0	0.6	13.0	ns

### $V_{CC} = 5V \pm 0.5V$ (see Figure 1)

Doromotor	From	то			25°C		-40°C t	o 85ºC	-40°C to	125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
4	^	V	C <sub>L</sub> =15pF	0.6	2.6	5.5	0.6	6.0	0.6	7.0	ns
<sup>l</sup> pd	A	r	C <sub>L</sub> =50pF	0.6	3.6	7.0	0.6	8.0	0.6	9.0	ns

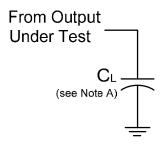


# **Operating Characteristics**

 $T_A = 25 \, {}^{\circ}C$ 

Parameter		Test Conditions	V <sub>CC</sub> = 5V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz No Load	8	pF

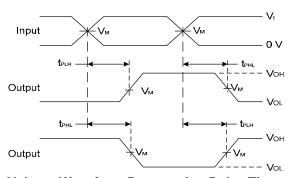
### **Parameter Measurement Information**



V	In	puts	V	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	C <sub>L</sub>
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF



**Voltage Waveform Pulse Duration** 



**Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs** 

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

-7



### **UNBUFFERED SINGLE INVERTER GATE**

### **Ordering Information**

T4AHC1G U04 XX - 7

Logic Device Function Package Packing

74 : Logic Prefix U04 : 1-Input W5 : SOT25 7 : Tape & Reel

AHC : 2 to 5.5V

Family 1G : One gate

SE

Unbuffered SE Inverter - Gate

SE: SOT353

3000/Tape & Reel

 Device
 Package Code
 Packaging (Note 5)
 7" Tape and Reel

 74AHC1GU04W5-7
 W5
 SOT25
 3000/Tape & Reel
 -7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

**SOT353** 

# **Marking Information**

74AHC1GU04SE-7

#### (Top View)

5 <u>XX</u>: Identification code Y: Year 0~9

 $\underline{XX} \underline{Y} \underline{W} \underline{X}$  \  $\underline{W}$ : Week:  $A^{Z}$ :  $1^{26}$  week;

a~z: 27~52 week; z represents

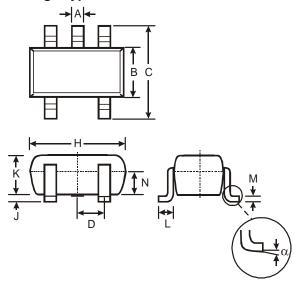
52 and 53 week X : A~Z : Internal code

Part Number	Package	Identification Code
74AHC1GU04W5	SOT25	YP
74AHC1GU04SE	SOT353	YP



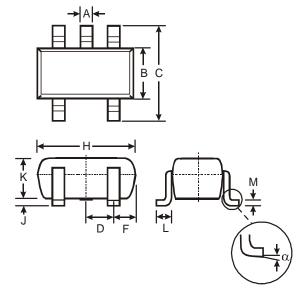
# Package Outline Dimensions (All Dimensions in mm)

# (1) Package Type: SOT25



SOT25									
Dim	Min	Max	Тур.						
Α	0.35	0.50	0.38						
В	1.50	1.70	1.60						
C	2.70	3.00	2.80						
D			0.95						
Η	2.90	3.10	3.00						
J	0.013	0.10	0.05						
K	1.00	1.30	1.10						
L	0.35	0.55	0.40						
M	0.10	0.20	0.15						
N	0.70	0.80	0.75						
α	0°	8°							
AII D	imens	ions i	n mm						

## (2) Package Type: SOT353



SOT353							
Dim	Min	Max					
Α	0.10	0.30					
В	1.15	1.35					
C	2.00	2.20					
D	0.65	Тур					
F	0.40	0.45					
Н	1.80	2.20					
J	0	0.10					
K	0.90	1.00					
٦	0.25	0.40					
М	0.10	0.22					
α	0°	8°					
All Din	nensions	in mm					



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